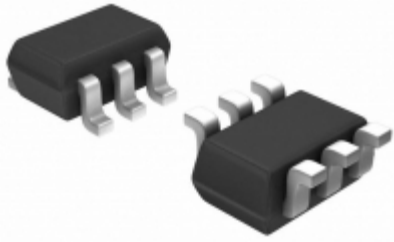










	<h2>SI1403CDL-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI1403CDL-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 2.1A SC-70-6</p> <p>Datenblätter:  SI1403CDL-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 32975 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1403CDL-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 2.1A SC-70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	32975 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Verlustleistung (max)	600mW (Ta), 900mW (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.1A (Tc)
Rds On (Max) @ Id, Vgs	140 mOhm @ 1.6A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	281pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)






















SI1403CDL-T1-GE3 ist neu im Original, Suche SI1403CDL-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1403CDL-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1403CDL-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI1403BDL-T1-GE3 Vishay Vishay SMD	 SI1403DL-T1-GE3 Vishay Precision Group SI1403DL-T1-GE3 VISHAY	 SI1403CDL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 2.1A SC-70-6	 SI1403DL-T1 VISHAY SI1403DL-T1 VISHAY
 SI1403BDL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 1.5A SC70-6	 SI1403BDL-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 1.4A SC70-6	 SI1403BDL-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 1.4A SC70-6	 SI1403DL VISHAY SI1403DL VISHAY

heiße Teile

Mehr

 SI1308EDL	 SI1308EDL-T1-GE3	 SI1308EDL-T1-GE3	D SI13132CNU	 SI1315DL-T1-GE3
 SI1315DL-T1-GE3	 SI1317DL-T1-GE3	D SI1317DL-T1-GE3	 SI1330EDL-T1-E3	 SI1330EDL-T1-E3
 SI1330EDL-T1-GE3	 SI1330EDL-T1-GE3	 SI1400DL-T1	 SI1400DL-T1-E3	 SI1400DL-T1-E3
D SI1400DL-T1-GE3	 SI1400DL-T1-GE3	 SI1401EDH-T1-GE3	 SI1401EDH-T1-GE3	 SI1402DH-T1-GE3
 SI1402DH-T1-GE3	 SI1403BDL-T1-E3	 SI1403BDL-T1-E3	 SI1403BDL-T1-GE3	 SI1403BDL-T1-GE3
 SI1403CDL-T1-GE3	 SI1403DL	D SI1403DL-T1	 SI1403DL-T1-E3	 SI1403DL-T1-GE3
 SI1404BDH-T1-E3	D SI1404BDH-T1-E3	 SI1404DH-T1	 SI1404DH-T1-E3	 SI1404DH-T1-GE3
 SI1404DL-T1-GE3	 SI1405BDH-T1-E3	 SI1405BDH-T1-E3	 SI1405BDH-T1-GE3	 SI1405BDH-T1-GE3
 SI1405DL-T1	 SI1405DL-T1-E3	 SI1405DL-T1-E3	D SI1406DH	 SI1406DH-T1
 SI1406DH-T1-E3	 SI1406DH-T1-E3	 SI1406DH-T1-GE3	 SI1406DH-T1-GE3	 SI1407DL

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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